



Three-Phase Brushless Motor Driver for OA Products

Overview

The LB11822 is a three-phase brushless motor driver that is optimal for driving drum and paper feed motors in laser printers and plain paper copiers. This IC adopts a direct PWM drive technique for minimal power loss. Flexible control of motor speed in response to an externally provided clock frequency (corresponding to the FG frequency) can be implemented by using the LB11822 in conjunction with the Sanyo LB11825M.

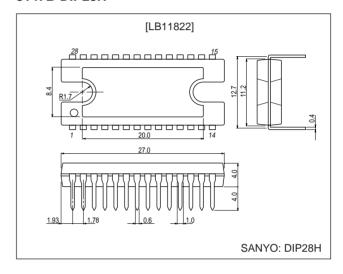
Functions and Features

- Three-phase bipolar drive (30 V, 3.1 A)
- · Direct PWM drive
- Built-in low side inductive kickback absorbing diode
- Speed discriminator + P_{LL} speed control
- · Speed locked state detection output
- · Built-in forward/reverse switching circuit
- Full complement of built-in protection circuits, including current limiter circuit, thermal protection circuit, and motor lock protection circuit.

Package Dimensions

unit: mm

3147B-DIP28H



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit	
Supply voltage	V _{CC} max		30	V	
Output current	I _O max	T ≤ 500 ms	3.1	Α	
Allowable power dissipation 1	Pd max1	Independent IC	3	W	
Allowable power dissipation 2	Pd max2	When infinitely large heat sink	20	W	
Operating temperature	Topr		-20 to +80	°C	
Storage temperature	Tstg		-55 to +150	°C	

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Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage range 1	V _{CC}		9.5 to 28	V
Voltage output current	I _{REG}		0 to - 30	mA
LD output current	ILD		0 to 15	mA

Electrical Characteristics at $Ta=25^{\circ}C,\,V_{CC}$ = VM = 24 V

Cumbal	Symbol Conditions Rating min typ		Ratings		Unit		
Symbol			typ	max	Onit		
I _{CC} 1			23	30	mA		
I _{CC} 2	When stopped		3.5	5	mA		
V _O sat1	I _O = 1.0 A, V _O (SINK)+ V _O (SOURCE)		2.0	2.5	V		
V _O sat2	I _O = 2.0 A, V _O (SINK)+ V _O (SOURCE)		2.6	3.2	V		
l _O leak				100	μA		
VD1	ID = -1.0 A		1.2	1.5	V		
VD2	ID = -2.0 A		1.5	2.0	V		
-!			!				
VREG	I _O = -5 mA	4.65	5.00	5.35	V		
ΔVREG1	V _{CC} = 9.5 to 28 V		30	100	mV		
ΔVREG2	$I_0 = -5 \text{ to } -20 \text{ mA}$		20	100	mV		
		'					
IHB		-2	-0.5		μA		
VICM		1.5		VREG-1.5	V		
1		80			mV _{P-P}		
ΔV _{IN}		15	24	42	mV		
VSLH			12		mV		
VSHL			-12		mV		
					<u> </u>		
V _{OH} (PWM)		2.5	2.8	3.1	V		
		1.2	1.5	1.8	V		
f(PWM)	C = 3900 pF		18		kHz		
V(PWM)		1.05	1.30	1.55	V _{P-P}		
V _{OH} (CSD)		3.6	3.9	4.2	V		
ICHG		-17	-12	-9	μA		
T(CSD)	C = 10 µF Design target value*		3.3		s		
		1					
VRF	V _{CC} -VM	0.45	0.5	0.55	V		
					<u> </u>		
TSD	Design target value* (junction temperature)	150	180		°C		
ΔTSD			50		°C		
Hysteresis ΔTSD Design target value* (junction temperature) 50 °C [FG Amplifier]							
VIO(FG)		-10		+10	mV		
IB(FG)		-1		+1	μA		
	IFGO = -0.2 mA	VREG-1.2	VREG-0.8		V		
	IFGO = 0.2 mA		0.8	1.2	V		
1	Gain: 100	3			mV		
	Design target value*	100	180	250	mV		
+				2	kHz		
+	f(FG) = 2 kHz	45	51		dB		
	I _{CC} 1	Icc1	Icc1	Symbol Conditions min typ	Symbol Conditions min typ max 23 30 30 10c2 When stopped 2.0 2.5 2.6 3.2 10 2.0 2.0 2.5 2.6 3.2 10 2.0 2.0 2.5 2.5 2.5 2.5 2.0 2.5		

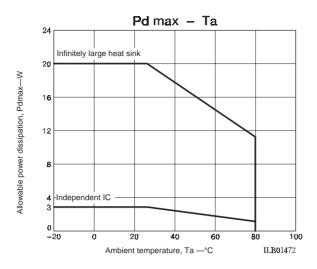
Note: * These are design target values and are not tested.

LB11822

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Parameter	Symbol	Conditions		Ratings		Unit	
- alameter symb		Conditions	min	typ	max		
[Speed Discriminator]							
Output H level voltage	V _{OH} (D)	IDO = -0.1 mA	VREG-1.0	VREG-0.7		V	
Output L level voltage	V _{OL} (D)	IDO = 0.1 mA		0.8	1.1	V	
Number of counts				512			
[PLL Output]							
Output H level voltage	V _{OH} (P)	IPO = -0.1 mA	VREG-1.8	VREG-1.5	VREG-1.2	V	
Output L level voltage	V _{OL} (P)	IPO = 0.1 mA	1.2	1.5	1.8	V	
[Lock Detection]							
Output L level voltage	V _{OL} (LD)	ILD = 10 mA		0.15	0.5	V	
Lock range				6.25		%	
[Integrator]							
Input bias current	IB(INT)		-0.4		+0.4	μΑ	
Output H level voltage	V _{OH} (INT)	IINTO = -0.2 mA	VREG-1.2	VREG-0.8		V	
Output L level voltage	V _{OL} (INT)	IINTO = 0.2 mA		0.8	1.2	V	
Open-loop gain		f(INT) = 1 kHz	45	51		dB	
Gain width product		Design target value*		450		kHz	
Reference voltage		Design target value*	-5%	VREG/2	5%	V	
[Clock Input Pin]			·				
Operating frequency range	fosc				1	MHz	
L level pin voltage	V _{OSCL}	$I_{OSC} = -0.5 \text{ mA}$		1.55		V	
H level pin current	losch	V _{OSC} = V _{OSCL} +0.5 V		0.4		mA	
[Start/Stop Pin]							
H level input voltage range	V _{IH} (S/S)		3.5		VREG	V	
L level input voltage range	V _{IL} (S/S)		0		1.5	V	
Input open voltage	V _{IO} (S/S)		VREG-0.5		VREG	V	
Hysteresis	ΔV_{IN}		0.35	0.50	0.65	V	
H level input current	I _{IH} (S/S)	V(S/S) = VREG	-10	0	10	μA	
L level input current	I _{IL} (S/S)	V(S/S) = 0 V	-280	-210		μA	
[Forward/Reverse Pin]	·		•				
H level input voltage range	V _{IH} (F/R)		3.5		VREG	V	
L level input voltage range	V _{IL} (F/R)		0		1.5	V	
Input open voltage	V _{IO} (F/R)		VREG-0.5		VREG	V	
Hysteresis	ΔV_{IN}		0.35	0.50	0.65	V	
H level input current	I _{IH} (F/R)	V(F/R) = VREG	-10	0	+10	μA	
L level input current	I _{IL} (F/R)	V(F/R) = 0 V	-280	-210		μA	

Note: * These are design target values and are not tested.

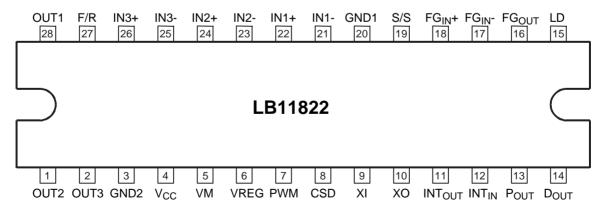


Truth Table

	Source F/R = "L"			F/R = "L"			
	Sink	IN1	IN2	IN3	IN1	IN2	IN3
1	OUT2 → OUT1	Н	L	Н	L	Н	L
2	OUT3 → OUT1	Н	L	L	L	Н	Н
3	OUT3 → OUT2	Н	Н	L	L	L	Н
4	OUT1 → OUT2	L	Н	L	Н	L	Н
5	OUT1 → OUT3	L	Н	Н	Н	L	L
6	OUT2 → OUT3	L	L	Н	Н	Н	L

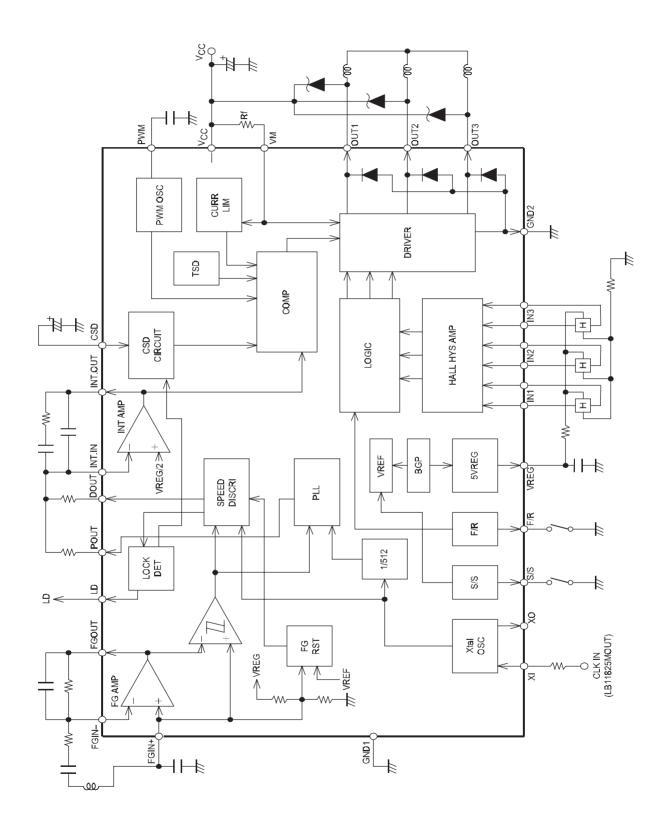
The relation between the clock frequency, fCLK, and the FG frequency, fFG, is given by the following equation.

Pin Assignment



Top view

Equivalent Circuit Block Diagram and Peripheral Circuits



Pin Function

Pin No.	Pin	Function	Equivalent circuit
28 1 2	OUT1 OUT2 OUT3	Motor drive output pin $ \label{eq:connect} \text{Connect the Schottky diode between the output} - V_{CC}. $	<u>VCC</u> 300 Ω VM 5
3	GND2	Output GND pin	1 2 28
5	VM	Power and output current detection pins of the output. Connect a low resistance (Rf) between this pin and V_{CC} . The output current is limited to the current value set with $I_{OUT} = VRF/Rf$.	3
4	V _{CC}	Power pin (Other than the output)	
6	VREG	Stabilized power supply output pin (5 V output) Connect a capacitor (about 0.1 µF) between this pin and GND for stabilization	VCC
7	PWM	Pin to set the PWM oscillation frequency. Connect a capacitor between this pin and GND. This can be set to about 18 kHz with C =3900 pF.	VREG 200 Ω 7
8	CSD	Pin to set the operation time of motor lock protection circuit. Connection of a capacitor (about 10 μ F) between CSD and GND can set the protection operation time of about 3.3seconds.	VREG 300 Ω 8

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Pin No.	Pin	Function	Equivalent circuit
9	XI XO	Clock input pin, which enters the clock signal (1 MHz or less) to the XI pin via resistor (about 5.1 k Ω). Keep the XO pin open.	VREG VREG
11	INT OUT	Integrating amplifier output (speed control pin).	VREG ORDER ORD
12	INT IN	Integrating amplifier input pin	VREG 300 Ω 12
13	Роит	PLL output pin	VREG 300 Ω 13

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Pin No.	Pin	Function	Equivalent circuit
14	DOUT	Speed discriminator output. Accelerate: high, decelerate: low	VREG 300 Ω 14
15	LD	Speed lock detection output. L when the motor speed is within the speed lock range (±6.25%). Voltage resistance 30 Vmax	VREG (15)
16	FG OUT	FG amplifier output pin	VREG GY OF FG schmidt comparator
17	FG _{IN} -	FG amplifier input pin. Connection of a capacitor (about 0.1 μF) between FG _{IN+} and	VREG FG Reset 18 300 Ω 17)
18	FG _{IN} +	GND causes initial reset to the logic circuit.	
19	S/S	Start/stop control pin. Low: 0 V to 1.5 V High: 3.5 V to VREG H level when open. Hysteresis width about 0.5 V	VREG G R R R R R R R R R R R R

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Pin No.	Pin	Function	Equivalent circuit
20	GND1	GND pin (Other than the output)	
22 21 24 23 26 25	IN1+ IN1- IN2+ IN2- IN3+ IN3-	Hall amplifier input. IN+ > IN- is the input high state, and the reverse is the input low state. It is recommended that the Hall signal has an amplitude of 100m Vp-p (differential) or more. Connect a capacitor between the IN+ and IN- inputs if there is noise in the Hall sensor signals.	VREG 300 Ω
27	F/R	Forward/reverse control pin Low: 0 V to 1.5 V High: 3.5 V to VREG H level when open Hysteresis width about 0.5 V	VREG GRAND 2 kΩ 27

Overview of the LB11822

1. Speed control circuit

This IC performs speed control by using both the speed discriminator circuit and PLL circuit. The speed control circuit outputs the error signal once for every two cycles of FG (one FG cycle counted). The PLL circuit outputs the phase error signal once for each cycle of FG.

As the FG servo frequency is calculated as follows, the motor speed is set with the number of FG pulses and clock frequency.

 $f_{FG}(servo) = f_{CLK}/512$

f_{CLK}: Clock frequency

This IC achieves variable speed control with ease when combined with LB11825M.

2. Output drive circuit

This IC employs a direct PWM drive method to minimize the power loss at output. The output Tr is always saturated at ON, and the motor drive force is adjusted through change of the duty at which the output is turned ON. Since the output PWM switching is made with the lower-side output Tr, it is necessary to connect the schottky diode between OUT and V_{CC} (because the through current flows at an instant when the lower-side Tr is turned Tr is turned Tr is turned Tr is turned Tr is not used). The diode between Tr is incorporated. When the large output current presents problem (waveform disturbance at kickback on the lower side), connect a commutating diode or schottky diode externally.

3. Current limiting circuit

The current limiting circuit performs limiting with the current determined from $I = V_{RF}/Rf$ ($V_{RF} = 0.5$ Vtyp, Rf: current detector resistance) (that is, this circuit limits the peak current).

Limiting operation includes decrease in the output on-duty to suppress the current.

4. Power save circuit

This IC enters the power save condition to decrease the current dissipation in the stop mode. In this condition, the bias current of most of circuits is cut off. Even in the power save condition, the 5 V regulator output is given.

5. Reference clock

This is entered from the external signal source (1 MHz max) via a resistor (reference: about 5.1 k Ω) in series with the XI pin. The XO pin is left open.

Input signal source levels: Low-level voltage: 0 to 0.8 V High-level voltage: 2.5 to 5.0 V

6. Speed lock range

The speed lock range is $\pm 6.25\%$ of the constant speed. If the motor speed falls inside the lock range, the LD pin goes to "L" (open collector output). When the motor speed falls outside the lock range, the on-duty ratio of motor drive output changes according to the speed error, causing control to keep the motor speed within the lock range.

7. PWM frequency

PWM frequency is determined from the capacity C (F) of capacitor connected to the PWM pin.

 $f_{PWM} \approx 1/(14,400 \times C)$

It is recommended to keep the PWM frequency at 15 kHz to 25 kHz

8. Hall input signal

The Hall input requires the signal input with an amplitude exceeding the hysteresis width (42 mV max). Considering the effect of noise, the input with the amplitude of 100 mV or more is recommended.

9. F/R changeover

Motor rotation direction can be changed over with the F/R pin. When changing F/R while the motor is running, pay attention to following points.

- For the through current at a time of changeover, the countermeasure is taken using a circuit. However, it is
 necessary to prevent exceeding of the rated voltage (30 V) due to rise of V_{CC} voltage at a time of changeover
 (because the motor current returns instantaneously to the power supply). When this problem exists, increase the
 capacity of a capacitor between V_{CC} and GND.
- When the motor current exceeds the current limit value after changeover, the lower-side Tr is turned OFF. But, the upper-side Tr enters the short-brake condition and the current determined from the motor counter electromotive voltage and coil resistance flows. It is necessary to prevent this current from exceeding the rated current (3.1 A). (F/R changeover at high speed is dangerous.)

10. Motor lock protection circuit

A motor lock protection circuit is incorporated for protection of IC and motor when the motor is locked.

When the LD output is "H" (unlocked) for a certain period in the start condition, the lower-side Tr is turned OFF. This time is set with the capacity of the capacitor connected to the CSD pin. The time can be set to about 3.3 seconds with the capacity of $10 \,\mu\text{F}$ (variance about $\pm 30\%$).

Set time (s)
$$\approx 0.33 \times C (\mu F)$$

When the capacitor used has a leak current, due consideration is necessary because it may cause error in the set time, etc.

Cancelling requires either the stop condition or re-application of power supply (in the stop condition). When the lock protection circuit is not to be used, connect the CSD pin to GND.

When the stop period during which lock protection is to be cancelled is short, the charge of capacitor cannot be discharged completely and the lock protection activation time at restart becomes shorter than the set value. It is necessary to provide the stop time with an allowance while referring to the following equation. (The same applies to restart in the motor start transient condition.)

Stop time (ms) $\geq 15 \times C (\mu F)$

line is particularly readily oscillated. The larger capacity need be selected.

11. Power supply stabilization

This IC has a large output current and is driven by switching, resulting in ready oscillation of the power line. It is therefore necessary to connect a capacitor with a sufficient capacity between the VCC pin and GND for stabilization. When a diode is inserted in the power line to prevent breakdown due to reverse connection of power supply, the power

12. Constant of integrating amplifier parts

Arrange the integrating amplifier external parts as near as possible to IC to protect them from noise effects. Arrange them by keeping the largest possible distance from the motor.

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